

Irish Standard I.S. EN 62258-2:2011

Semiconductor die products -- Part 2: Exchange data formats (IEC 62258 -2:2011 (EQV))

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English version

Semiconductor die products -Part 2: Exchange data formats (IEC 62258-2:2011)

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This European Standard was approved by CENELEC on 2011-06-29. CENELEC members are bound to comply with the CEN/CENELEC Internal Regulations which stipulate the conditions for giving this European Standard the status of a national standard without any alteration.

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CENELEC

European Committee for Electrotechnical Standardization Comité Européen de Normalisation Electrotechnique Europäisches Komitee für Elektrotechnische Normung

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Foreword

The text of document 47/2085/FDIS, future edition 2 of IEC 62258-2, prepared by IEC TC 47, Semiconductor devices, was submitted to the IEC-CENELEC parallel vote and was approved by CENELEC as EN 62258-2 on 2011-06-29.

This European Standard supersedes EN 62258-2:2005.

With respect to EN 62258-2:2005, the following parameters have been updated for EN 62258-2:2011:

Subclause	Parameter name
8.2.9	DEVICE_PICTURE_FILE
8.2.10	DEVICE DATA FILE
8.4.6	TERMINAL GROUP
8.4.7	PERMUTABLE
8.5.1	TERMINAL_MATERIAL (was DIE TERMINAL MATERIAL)
8.5.2	TERMINAL_MATERIAL_STRUCTURE
8.6.2	MAX_TEMP_TIME
8.7.6	SIMULATOR_simulator_TERM_GROUP
8.8.3	ASSEMBLY
8.9.2	WAFER_THICKNESS
8.9.3	WAFER_THICKNESS_TOLERANCE
8.9.9	WAFER_INK
8.10.4	BUMP_SHAPE
8.10.5	BUMP_SIZE
8.10.6	BUMP_SPECIFICATION_DRAWING
8.10.7	BUMP_ATTACHMENT_METHOD
8.11.4	MPD_MSL_LEVEL
8.11.5	MPD_PACKAGE_DRAWING
8.12.1	QUALITY
8.12.2	TEST
8.13.1	TEXT
8.14.1	PARSE

This standard shall be read in conjunction with EN 62258-1.

Attention is drawn to the possibility that some of the elements of this document may be the subject of patent rights. CEN and CENELEC shall not be held responsible for identifying any or all such patent rights.

The following dates were fixed:

 latest date by which the EN has to be implemented at national level by publication of an identical national standard or by endorsement

(dop) 2012-03-29

 latest date by which the national standards conflicting with the EN have to be withdrawn

(dow) 2014-06-29

Annex ZA has been added by CENELEC.

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EN 62258-2:2011

Endorsement notice

The text of the International Standard IEC 62258-2:2011 was approved by CENELEC as a European Standard without any modification.

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Annex ZA (normative)

Normative references to international publications with their corresponding European publications

The following referenced documents are indispensable for the application of this document. For dated references, only the edition cited applies. For undated references, the latest edition of the referenced document (including any amendments) applies.

NOTE When an international publication has been modified by common modifications, indicated by (mod), the relevant EN/HD applies.

<u>Publication</u>	<u>Year</u>	<u>Title</u>	EN/HD	<u>Year</u>
IEC 61360-4	2005	Standard data element types with associated classification scheme for electric components Part 4: IEC reference collection of standard data element types and component classes		2005 2005
IEC 62258-1	-	Semiconductor die products - Part 1: Procurement and use	EN 62258-1	-
ISO 6093	1985	Information processing - Representation of numerical values in character strings for information interchange	-	-
ISO 8601	2004	Data elements and interchange formats - Information interchange - Representation of dates and times	-	-
ISO 10303-21	2002	Industrial automation systems and integration - Product data representation and exchange - Part 21: Implementation methods: Clear text encoding of the exchange structure		-
IPC/JEDEC J-STD-033B	2007	Handling, Packing, Shipping and Use of Moisture/Reflow Sensitive Surface Mount Devices	-	-

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INTERNATIONAL ELECTROTECHNICAL COMMISSION

SEMICONDUCTOR DIE PRODUCTS -

Part 2: Exchange data formats

FOREWORD

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International Standard IEC 62258-2 has been prepared by IEC technical committee 47: Semiconductor devices.

This standard shall be read in conjunction with IEC 62258-1.

This second edition cancels and replaces the first edition published in 2005, and constitutes a technical revision.

With respect to the first edition, the following parameters have been updated for this edition:

Subclause	Parameter name			
8.2.9	DEVICE_PICTURE_FILE			
8.2.10	DEVICE_DATA_FILE			
8.4.6	TERMINAL_GROUP			
8.4.7	PERMUTABLE			
8.5.1	TERMINAL_MATERIAL			
	(was DIE_TERMINAL_MATERIAL)			
8.5.2	TERMINAL_MATERIAL_STRUCTURE			
8.6.2	MAX_TEMP_TIME			
8.7.6	SIMULATOR_simulator_TERM_GROUP			
8.8.3	ASSEMBLY			
8.9.2	WAFER_THICKNESS			
8.9.3	WAFER_THICKNESS_TOLERANCE			
8.9.9	WAFER_INK			
8.10.4	BUMP_SHAPE			
8.10.5	BUMP_SIZE			
8.10.6	BUMP_SPECIFICATION_DRAWING			
8.10.7	BUMP_ATTACHMENT_METHOD			
8.11.4	MPD_MSL_LEVEL			
8.11.5	MPD_PACKAGE_DRAWING			
8.12.1	QUALITY			
8.12.2	TEST			
8.13.1	TEXT			
8.14.1	PARSE			

The text of this standard is based on the following documents:

FDIS	Report on voting
47/2085/FDIS	47/2095/RVD

Full information on the voting for the approval of this standard can be found in the report on voting indicated in the above table.

This publication has been drafted in accordance with the ISO/IEC Directives, Part 2.

The committee has decided that the contents of this publication will remain unchanged until the stability date indicated on the IEC web site under "http://webstore.iec.ch" in the data related to the specific publication. At this date, the publication will be

- reconfirmed,
- withdrawn,
- · replaced by a revised edition, or
- amended.

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INTRODUCTION

This International Standard is based on the work carried out in the ESPRIT 4th Framework project GOODDIE which resulted in publication of the ES 59008 series of European specifications. Organisations that helped prepare this document include the ESPRIT ENCAST and ENCASIT projects, the Die Products Consortium, JEITA, JEDEC and ZVEI.

The structure of this International Standard as currently conceived is as follows:

Under main title: IEC 62258: Semiconductor die products

Part 1: Procurement and use
Part 2: Exchange data formats

Part 3: Recommendations for good practice in handling, packing and storage

(Technical report)

Part 4: Questionnaire for die users and suppliers (Technical report)
Part 5: Requirements for information concerning electrical simulation
Part 6: Requirements for information concerning thermal simulation

Part 7: XML schema for data exchange (Technical report)

Part 8: EXPRESS model schema for data exchange (Technical report)

Further parts may be added as required.

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SEMICONDUCTOR DIE PRODUCTS -

Part 2: Exchange data formats

1 Scope and object

This Part of IEC 62258 specifies the data formats that may be used for the exchange of data which is covered by other parts of the IEC 62258 series, as well as definitions of all parameters used according to the principles and methods of IEC 61360. It introduces a Device Data Exchange (DDX) format, with the prime goal of facilitating the transfer of adequate geometric data between die manufacturer and CAD/CAE user and formal information models that allow data exchange in other formats such as STEP physical file format, in accordance with ISO 10303-21, and XML. The data format has been kept intentionally flexible to permit usage beyond this initial scope.

It has been developed to facilitate the production, supply and use of semiconductor die products, including but not limited to:

- wafers,
- · singulated bare die,
- die and wafers with attached connection structures,
- minimally or partially encapsulated die and wafers.

This standard reflects the DDX data format at version 1.3.0

2 Normative references

The following referenced documents are indispensable for the application of this document. For dated references, only the edition cited applies. For undated references, the latest edition of the referenced document (including any amendments) applies.

IEC 62258-1, Semiconductor die products – Part 1: Procurement and use

IEC 61360-4:2005, Standard data element types with associated classification scheme for electric components – Part 4: IEC reference collection of standard data element types, component classes303-21

ISO 8601:2004, Data elements and interchange formats – Information interchange – Representation of dates and times

ISO 6093:1985, Information processing – Representation of numerical values in character strings for information interchange

IPC/JEDEC J-STD-033B:2007, Handling, Packing, Shipping and Use of Moisture/Reflow Sensitive Surface Mount Devices

ISO 10303-21:2002, Industrial automation systems and integration – Product data representation and exchange – Part 21: Implementation methods: Clear text encoding of the exchange structure



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